NSN 5961-00-827-9989 Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.190 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.187 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-72
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
5.0 emitter to base voltage, static, collector open all transistor
Current Rating Per Characteristic:
400.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0